

U.S. Patent No. 6,927,152
Request for Certificate of Correction

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PATENT
Docket: CU-3494

APR 10 2007

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application: Seung Woo JIN et al.

] GRP ART UNIT: 2823

Patent No: 6,927,152

Issue Date: August 9, 2005

] Ex.: Dang, Trung Q.

Serial No: 10/738,394

Filed: December 17, 2003

For: METHOD FOR FABRICATING SEMICONDUCTOR DEVICE

Certification under 37 C.F.R. §1.8(a)

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I hereby certify that this paper (along with any paper referred to as being attached or enclosed) is being transmitted to the United States Patent and Trademark Office to the fax number and on the date indicated above.

Anthony E. Anderson

**REQUEST FOR CERTIFICATE OF CORRECTION TO CORRECT ERRORS IN
PATENT DUE TO APPLICANT'S MISTAKE (37 CFR 1.323)**

Certificate of Corrections Branch

The Commissioner for Patents

P.O. Box 1450

Alexandria VA 22313-1450

Dear Sir:

This is a Request for Certificate of Correction to correct an inadvertent typographical error in claim 6 of U.S. Patent No. 6,927,152 (col. 4, line 31) and is summarized as follows:

APPLICANT'S MISTAKE (37 CFR 1.323)

With respect to Section (57) of the patent, it is noted that there is a minor typographical error in claim 6 (col. 4, line 31). A request under 35 U.S.C. 255 to correct

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the minor typographical error is submitted herein.

Claim 6 reads as follows, inter alia:

"...implantation energy of 1040KeV and a dose of 1.0E15-1.0E16."

and should read as follows:

"...implantation energy of ~~-10—40KeV—~~ and a dose of 1.0E15-1.0E16."

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